



N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _A = +25°C
2017	$46m\Omega$ @ V _{GS} = $4.5V$	3.1A
20V	$53m\Omega$ @ V _{GS} = 2.5V	2.8A

Features and Benefits

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

Description and Applications

This MOSFET is designed to minimize the on-state resistance (RDS(ON)) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- General Purpose Interfacing Switch
- **Power Management Functions**
- **DC-DC Converters**
- Analog Switch

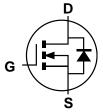
Mechanical Data

- Case: SOT323
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (63)
- Weight: 0.027 grams (Approximate)

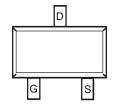








Equivalent Circuit



Top View Pin-Out

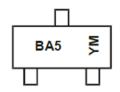
Ordering Information (Note 4)

Part Number	Case	Packaging
DMN2055UW-7	SOT323	3,000/Tape & Reel
DMN2055UW-13	SOT323	10,000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

Marking Information



BA5 = Product Type Marking Code YM or $\overline{Y}M$ = Date Code Marking Y or \overline{Y} = Year (ex: H = 2020) M = Month (ex: 9 = September)

Date Code Key

Year	2019	2020	2021	2022	2023	2024	2025	2026	2027	2028	2029	2030
Code	G	Н		J	K	L	М	N	0	Р	R	S
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec



Maximum Ratings (@ $T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	VDSS	20	V		
Gate-Source Voltage			V_{GSS}	±8	V
	Steady	T _A = +25°C		3.1	
Continuous Drain Current (Note 6) V _{GS} = 4.5V	ID	2.4	A		
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%	I _{DM}	22	Α		
Maximum Body Diode Forward Current (Note 5)			Is	0.8	Α

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

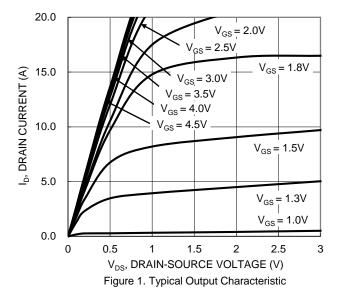
Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)		PD	0.52	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	RθJA	241	°C/W
Total Power Dissipation (Note 6)		P _D	0.65	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	$R_{\theta JA}$	191	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)	- CyDC.		. , , ,	mux	- Oille	root containen
Drain-Source Breakdown Voltage	BVDSS	20	_	_	V	V _G S = 0V, I _D = 250µA
Zero Gate Voltage Drain Current @T _C = +25°C	I _{DSS}	_	_	1.0	μΑ	V _{DS} = 20V, V _{GS} = 0V
Gate-Source Leakage	Igss	_	_	±100	nA	$V_{GS} = \pm 8V$, $V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	Vgs(TH)	0.4	_	1.0	V	$V_{DS} = V_{GS}$, $I_D = 250\mu A$
Ctatia Dunia Causaa On Basistanaa	1	_	35	46	0	Vgs = 4.5V, ID = 3.6A
Static Drain-Source On-Resistance	RDS(ON)	_	39	53	mΩ	V _{GS} = 2.5V, I _D = 3.1A
Diode Forward Voltage	VsD	_	0.7	1	V	V _G S = 0V, I _S = 1A
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss		400		pF	10,40,40,4
Output Capacitance	Coss		55		pF	V _{DS} = 10V, V _{GS} = 0V, - f = 1.0MHz
Reverse Transfer Capacitance	Crss		37		pF	I = 1.0WI IZ
Gate Resistance	R_g	_	3.7	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$
Total Gate Charge	Qg	_	4.3	_	nC	\\ 45\\\\ 10\\\
Gate-Source Charge	Qgs	_	0.3	_	nC	$V_{GS} = 4.5V, V_{DS} = 10V,$ -In = 6A
Gate-Drain Charge	Q_{gd}		4.8		nC	ID = 6A
Turn-On Delay Time	t _{D(ON)}	_	2.8	_	ns	
Turn-On Rise Time	t _R	_	2.7	_	ns	$V_{DD} = 10V$, $V_{GS} = 5V$,
Turn-Off Delay Time	tD(OFF)	_	15.4	_	ns	$R_L = 1.7\Omega$, $R_g = 6\Omega$
Turn-Off Fall Time	tF	_	4.4	_	ns	

- 5. Device mounted on FR-4 substrate PC board, with minimum recommended pad layout.
 6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
 7. Short duration pulse test used to minimize self-heating effect.
 8. Guaranteed by design. Not subject to product testing.





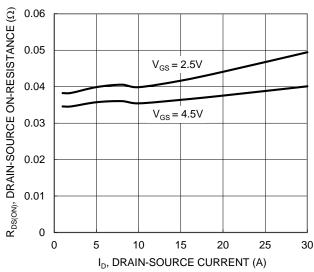


Figure 3. Typical On-Resistance vs. Drain Current and Gate Voltage

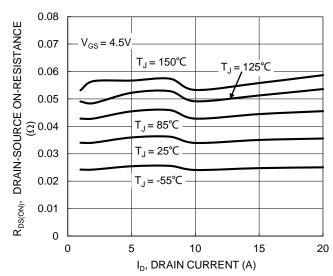


Figure 5. Typical On-Resistance vs. Drain Current and Junction Temperature

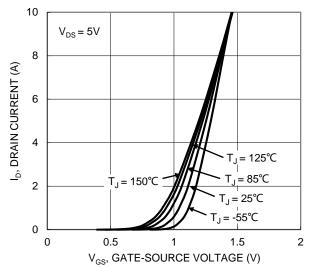


Figure 2. Typical Transfer Characteristic

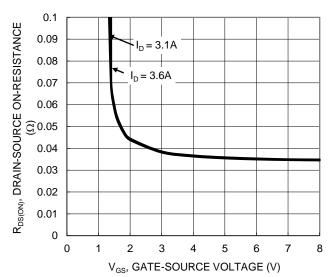


Figure 4. Typical Transfer Characteristic

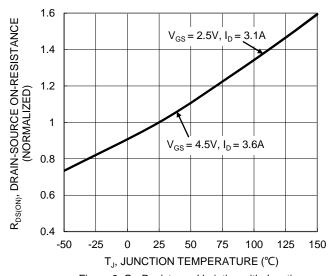


Figure 6. On-Resistance Variation with Junction Temperature



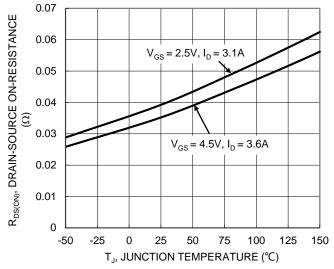


Figure 7. On-Resistance Variation with Junction Temperature

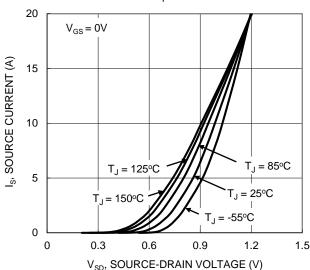


Figure 9. Diode Forward Voltage vs. Current

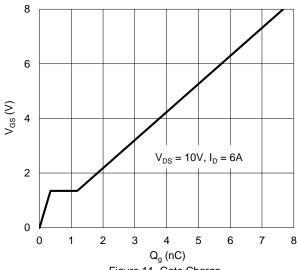


Figure 11. Gate Charge

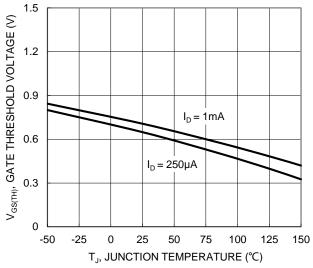


Figure 8. Gate Threshold Variation vs. Junction Temperature

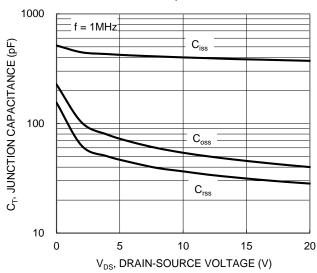
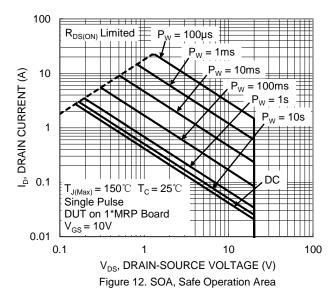


Figure 10. Typical Junction Capacitance





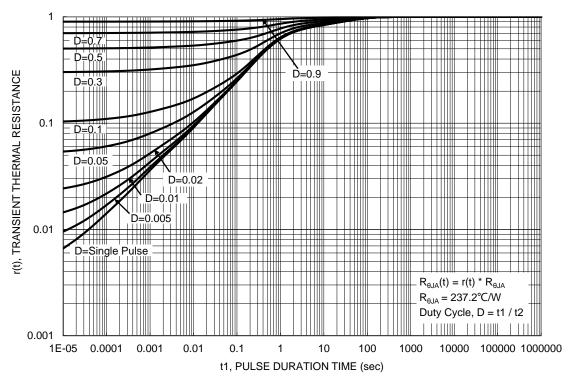


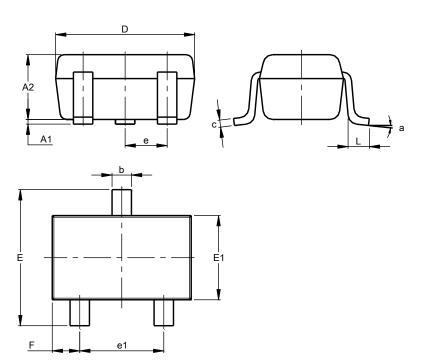
Figure 13. Transient Thermal Resistance



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT323

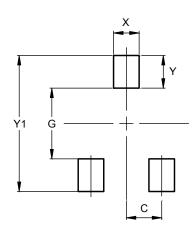


SOT323								
Dim	Min	Max	Тур					
A1	0.00	0.10	0.05					
A2	0.90	1.00	0.95					
b	0.25	0.40	0.30					
С	0.10	0.18	0.11					
D	1.80	2.20	2.15					
Е	2.00	2.20	2.10					
E1	1.15	1.35	1.30					
е	().650 B	SC					
e1	1.20	1.40	1.30					
F	0.375 0.475 0.425							
L	0.25	0.40	0.30					
а	0°	8°						
All Dimensions in mm								

Suggested Pad Layout

 $\label{prop:lease} Please see \ http://www.diodes.com/package-outlines.html \ for \ the \ latest \ version.$

SOT323



Dimensions	Value (in mm)		
С	0.650		
G	1.300		
X	0.470		
Y	0.600		
V1	2.500		



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